Schottky Diode Termination Network



QDN001 Series

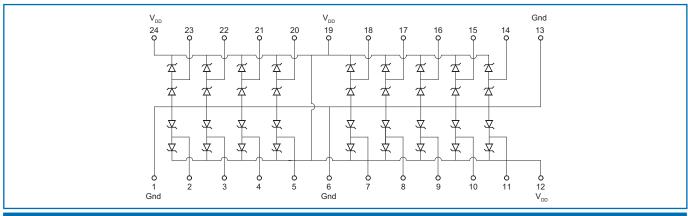
- Suitable for high speed memory bus applications
- RoHS compliant and Sn/Pb terminations available
- Reduces overshoot and undershoot for all data line types
- Effective termination for both controlled/uncontrolled line terminations
- 36 Schottky diodes integrated in a QSOP package for fast turn-on/reverse recovery characteristics

Rever

Electrical Data

Parameter	Min Value	Max Value
Operating Voltage (V _{DD})	-0.3V	7.0V
Diode Forward Voltage		
Forward Current = 10mA Forward Current = 50mA	N/A	0.5V 0.8V
Channel Input Capacitance ($V_{IN} = 2.5V, V_{DD} = 5V, T = 25^{\circ}C$)	N/A	5pF
ESD Protection MIL-STD-883 Method 3015	N/A	±4KV
Channel Leakage Current (T = 25°C) (0 $V_{IN} V_{DD}$)	N/A	0.1µA
Channel Clamp Current	N/A	±50mA
Package Power Rating	N/A	1.0W
Operating Temperature Range	0°C	+70°C
Storage Temperature Range	-65°C	+150°C

Schematic Data



General Note

IRC reserves the right to make changes in product specification without notice or liability. All information is subject to IRC's own data and is considered accurate at time of going to print.

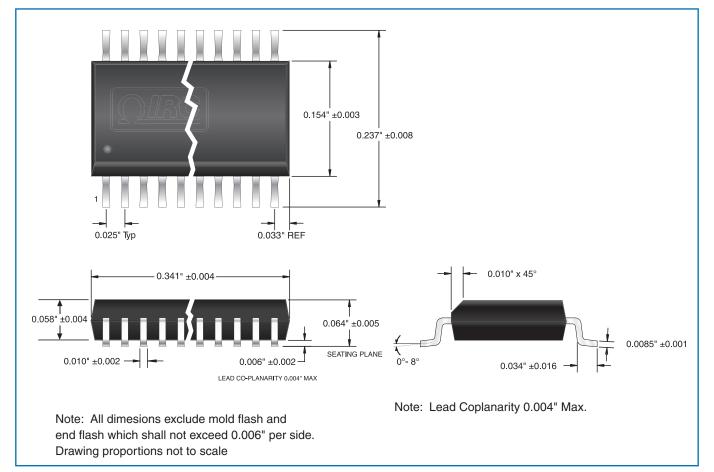
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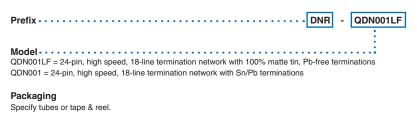
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Physical Data



Ordering Data



For additional information or to discuss your specific requirements, please contact our Applications Team using the contact details below.

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